T1650H-6E 16A TRIAC

Rev.A.1.1

DESCRIPTION:

The T1650H-6E -6E

Peak pulse voltage (T_j=25 ; non-repetitive,off-state;FIG.8)	V_{pp}	4	kV

ELECTRICAL CHARACTERISTICS (T_j=25 unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
I_{GT}	V_D =12V R_L =33Ω	- -	MAX.	50	mA
V_{GT}		- -	MAX.	1	V
V_{GD}	V_D =V_{DRM} T_j =150 R_L =3.3kΩ	- -	MIN.	0.2	V
I_L	I_G =1.2I_{GT}	-	MAX.	80	mA
				100	
I_H	I_T =500mA		MAX.	60	mA
dV/dt	V_D=400V Gate Open T_j =150		MIN.	2000	V/μs
(dI/dt)c	(dV/dt)c=20V/μs, T_j=150		MIN.	25	A/ms
t_{on}	I_G=80mA I_A=400mA I_R=40mA T_j=25		TYP.	12	μs
t_{off}				80	

STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX.)	Unit
V_{TM}	I_{TM} =22.5A t_p=380μs	T_j=25	1.4	V
V_{TO}	Threshold voltage	T_j=150	0.75	V
R_D	Dynamic resistance	T_j=150	27	mΩ
I_{DRM}	V_D =V_{DRM} V_R =V_{RRM}	T_j=25	5	μA
I_{RRM}		T_j=150	1.5	mA

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	junction to case (AC)	1.2	/W
$R_{th(j-a)}$	junction to ambient (AC)	45	/W

ORDERING INFORMATION

T 16 50 H -6 E -/

- T: Triacs
- 16: $I_{T(RMS)}$:16A
- 50: I_{GT1-3} 50mA
- H: High junction temperature
- -6: V_{DRM} /V_{RRM} 600V
- E: TO-263
- -/: Blank:Tube; -TR:Tape & Reel

MARKING

FIG.1: Maximum power dissipation versus RMS on-state current

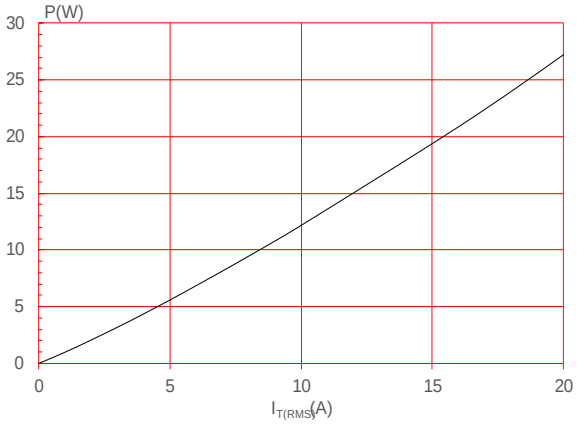


FIG.2: RMS on-state current versus case temperature

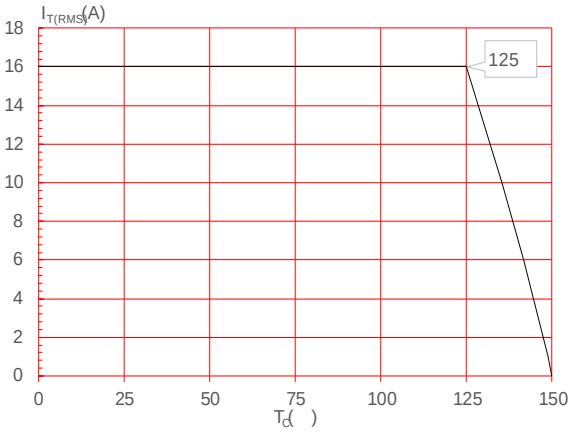


FIG.3: RMS on-state current versus ambient temperature (printed circuit board FR4,copper thickness:35μm)(full cycle)

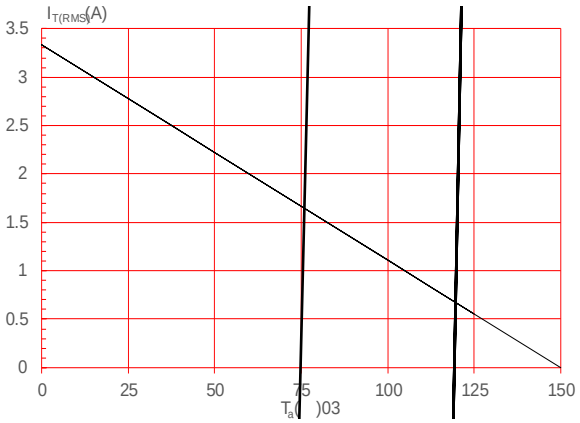


FIG.4: Surge peak on-state current versus number of cycles

FIG.7: Relative variations of gate trigger current, holding current and latching current versus junction temperature

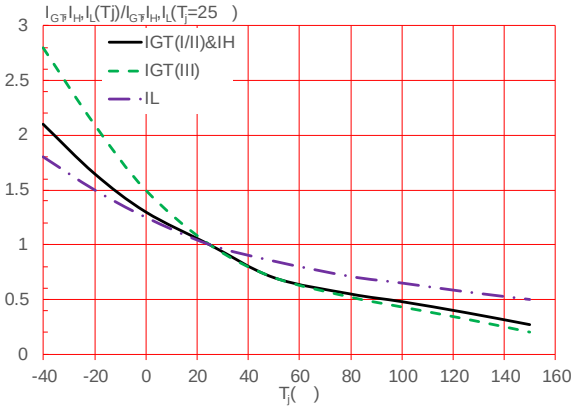
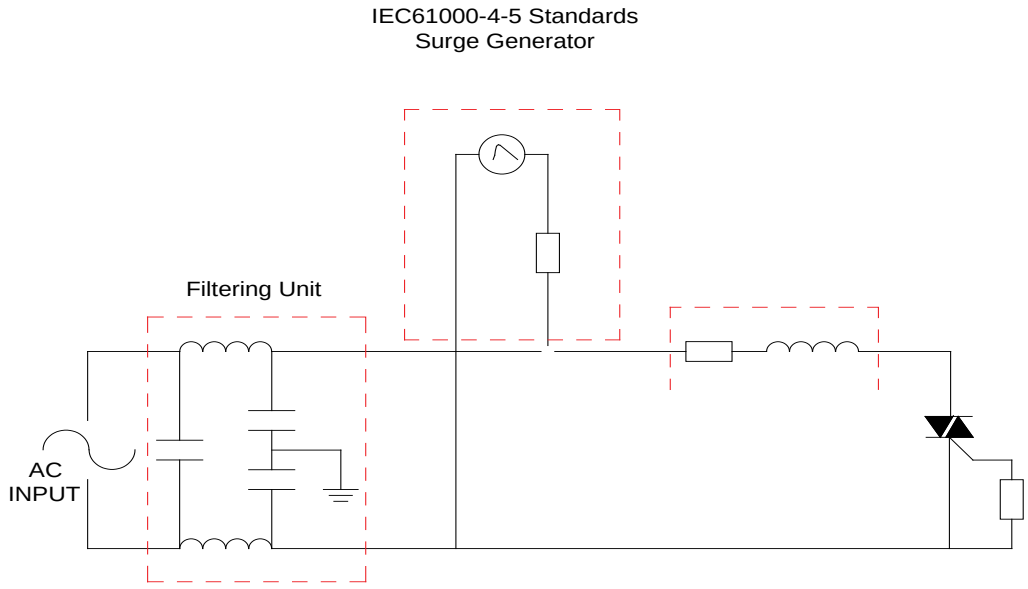
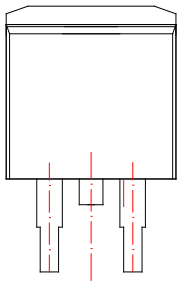


FIG.8 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards

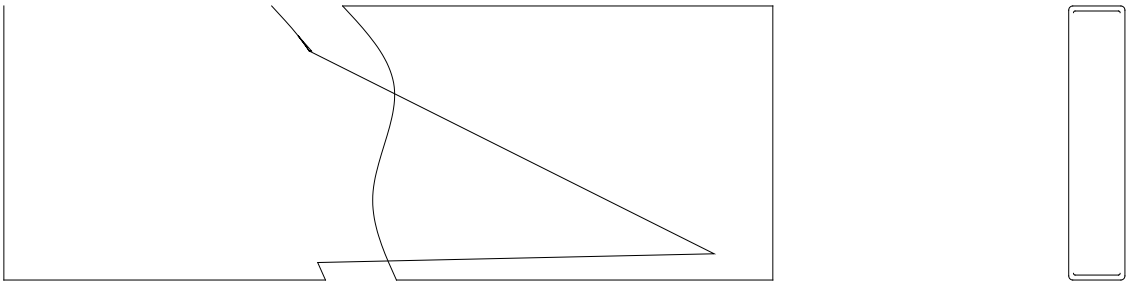


PACKAGE MECHANICAL DATA



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	9.90		10.20	0.390		0.402
B	14.70		15.80	0.579		0.622
C	9.40		9.60	0.370		0.378
D	2.40			0.094		
E	1.20		1.50	0.047		0.059
F	0.75		0.85	0.029		0.033

DELIVERY MODE



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